

## General Description

These Silicon N-channel enhanced vdmosfets, is obtained by the self-aligned planar used technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy. Which accords with the RoHS standard.

## Features

- Fast switching
- Extended Safe Operating Area
- Ease of Paralleling
- 100% avalanche tested

## Mechanical Data

- Case:TO-220,TO-220C,TO-263,TO-262,TO-251,TO-252,ITO-220 Package

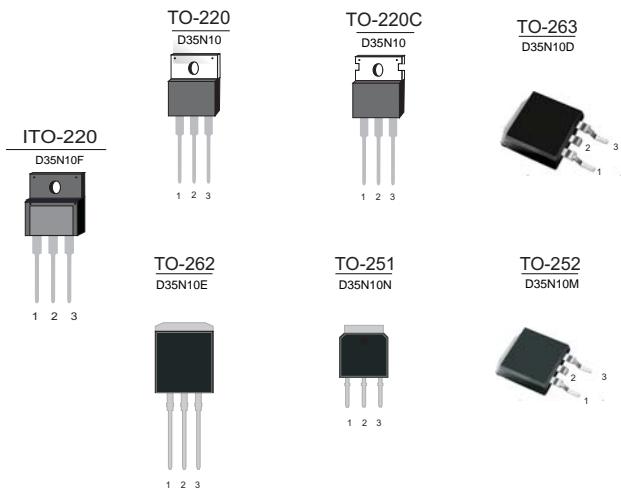
## Application

- Power switching application
- DC Motor Control
- UPS

## Ordering Information

Part No.	Package Type	Package	Quality(box)
D35N10	TO-220/C	Tube	1000
D35N10D	TO-263	Tape & Reel	800
D35N10E	TO-262	Tube	1000
D35N10N	TO-251	Tube	1000
D35N10M	TO-252	Tape & Reel	3000
D35N10F	ITO-220	Tube	1000

Product Summary			
V <sub>DS</sub>	R <sub>D(on)</sub> (mΩ) Typ	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ)
100V	35@ 10V	35	40nC



## Pin Definition:

1. Gate
2. Drain
3. Source

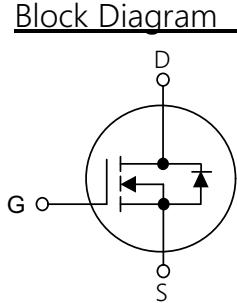


Table1 Absolute Maximum Ratings (T<sub>c</sub>=25°C, unless otherwise specified)

Parameter	Symbol	TO-220/TO-263/TO-262 TO-252/TO-251/TO-220C	ITO-220	Unit
Drain-Source Voltage	V <sub>DS</sub>	100		V
Gate-Source Voltage	V <sub>GS</sub>	±25		V
Continuous Drain Current <small>T<sub>c</sub>=25°C</small>	I <sub>D</sub>	35		A
		21		
Pulsed Drain Current (Note 1)	I <sub>DM</sub>	85		A
Single Pulse Avalanche Energy	E <sub>AS</sub>	480		mJ
Power Dissipation T <sub>c</sub> =25°C	P <sub>D</sub>	50	34	W
Operating Junction and Storage Temperature	T <sub>J</sub> /T <sub>STG</sub>	-55 ~ +175		°C

Table 2.Thermal Characteristics

Parameter	Symbol	TO-220/TO-263/TO-262 TO-252/TO-251/TO-263-7	ITO-220	Unit
Thermal resistance Junction to Ambient	R <sub>θJA</sub>	90.0	90.0	°C/W
Thermal resistance Junction to Case	R <sub>θJC</sub>	3.00	4.50	°C/W

Table 3. Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise specified)

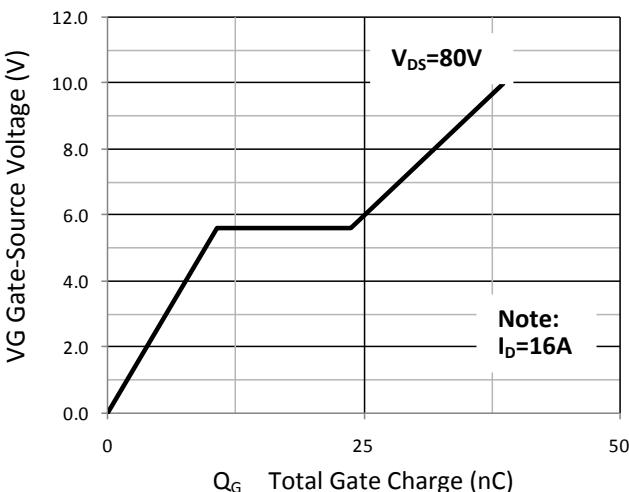
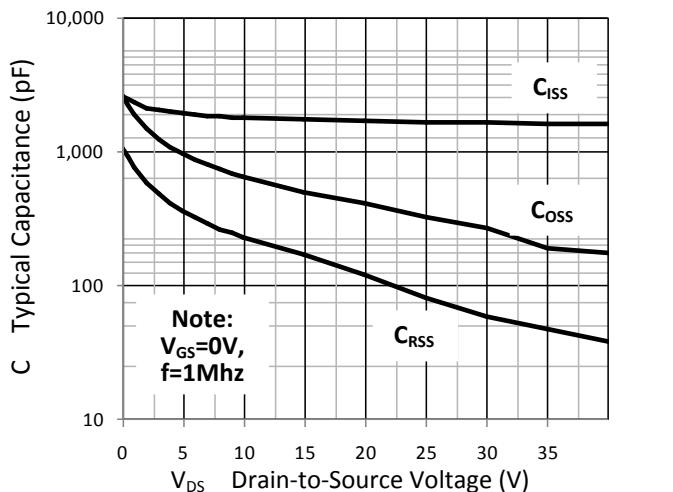
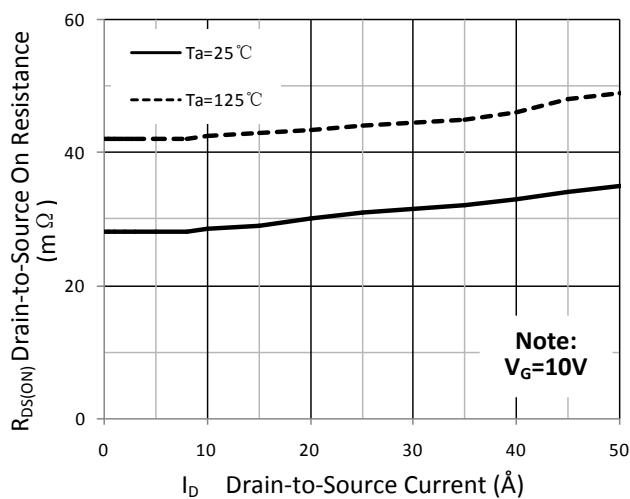
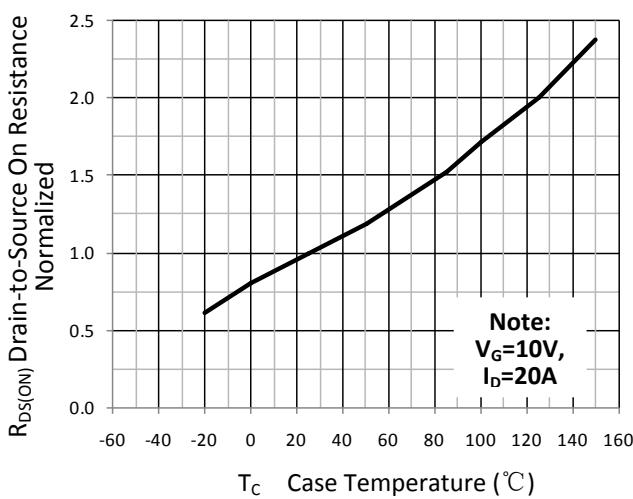
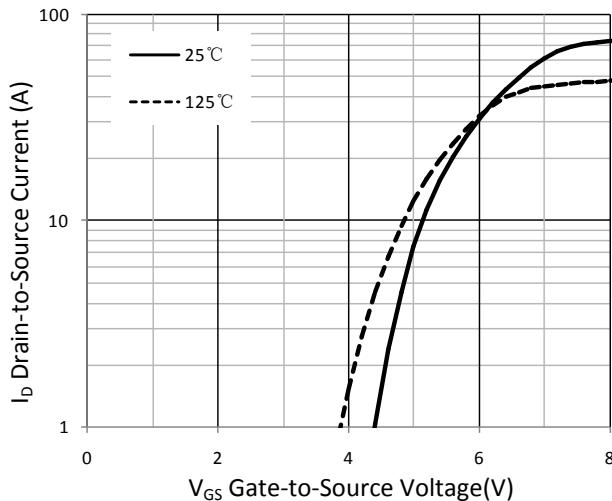
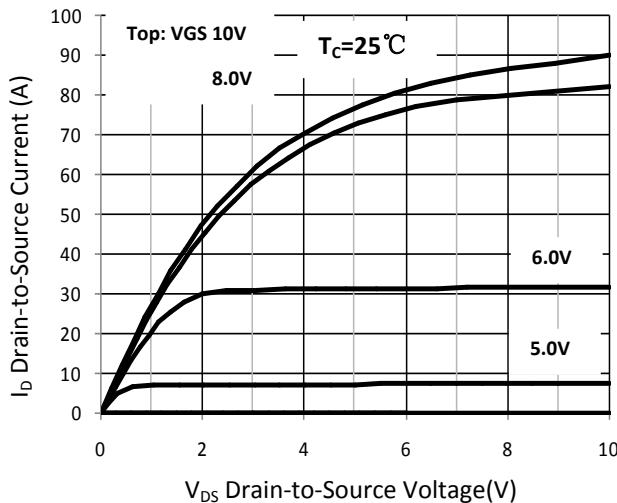
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	V <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250μA	100			V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V			2	μA
Gate- Source Leakage Current	Forward	I <sub>GSS</sub>	V <sub>GS</sub> =25V,V <sub>DS</sub> =0V		100	nA
	Reverse		V <sub>GS</sub> =-25V,V <sub>DS</sub> =0V		-100	nA
<b>On Characteristics(Note 4)</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	2		4	V
Static Drain-Source On-State Resistance	R <sub>DSS(ON)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =20A		35	43	mΩ
<b>Dynamic Characteristics(Note 5)</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,f=1MHz		1650		pF
Output Capacitance	C <sub>oss</sub>			320		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			80		pF
<b>Switching Characteristics (Note 5)</b>						
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =50V,I <sub>D</sub> =16A, V <sub>GS</sub> =10V , R <sub>G</sub> =5.1Ω		15		ns
Turn-On Rise Time	t <sub>r</sub>			39		ns
Turn-Off Delay Time	t <sub>d(off)</sub>			40		ns
Turn-Off Fall Time	t <sub>f</sub>			33		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DS</sub> =80V,I <sub>D</sub> =16A, V <sub>GS</sub> =10V		40		nC
Gate-Source Charge	Q <sub>GS</sub>			12		nC
Gate-Drain Charge	Q <sub>GD</sub>			15		nC
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A		0.87	1.2	V
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>				35	A
Reverse Recovery Time	t <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>F</sub> =16A dI <sub>F</sub> /dt=100A/μs		60		ns
Reverse Recovery Charge	Q <sub>RR</sub>			135		nC

Notes : 1 Repetitive Rating:Pulse width limited by maximum junction temperature

4 Pulse Test: Pulse width ≤300μS,Duty cycle≤2%

5 Guaranteed by design,not subject to production

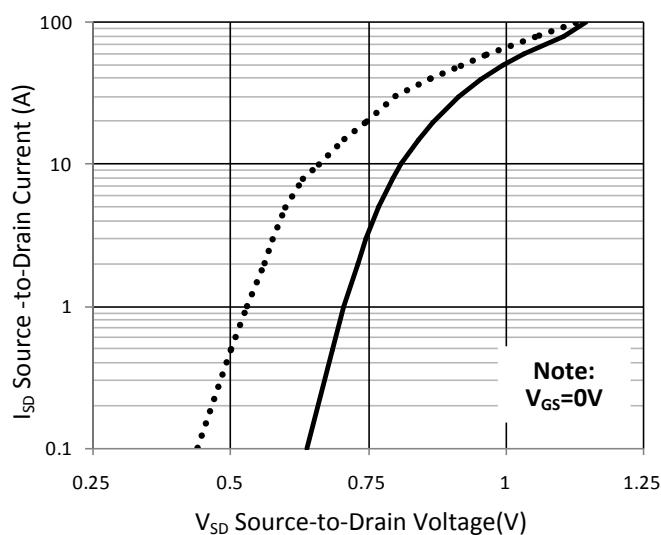
### Typical Characteristics Diagrams



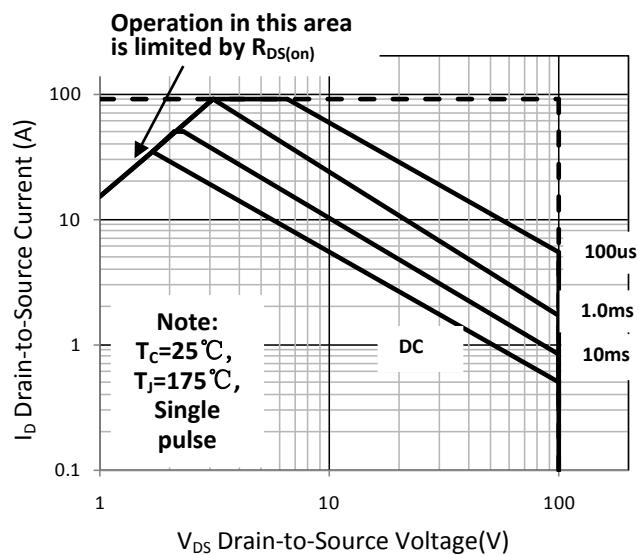
**Figure 5. Typical Capacitance Vs Drain-Source Voltage**

**Figure 6. Typical Gate Charge Vs Gate-Source Voltage**

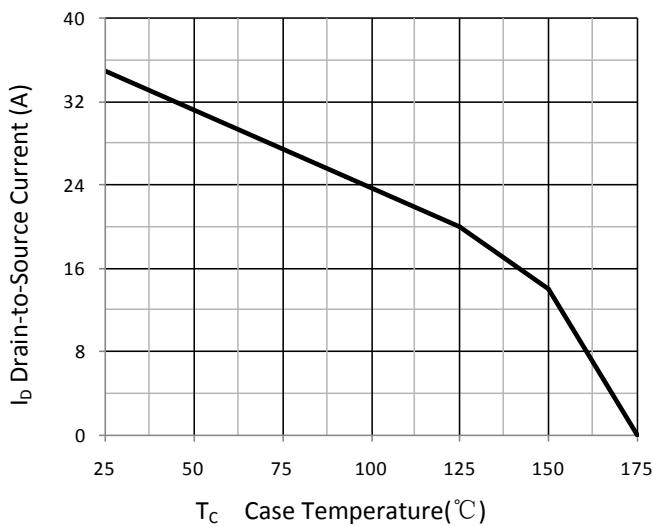
### Typical Characteristics Diagrams



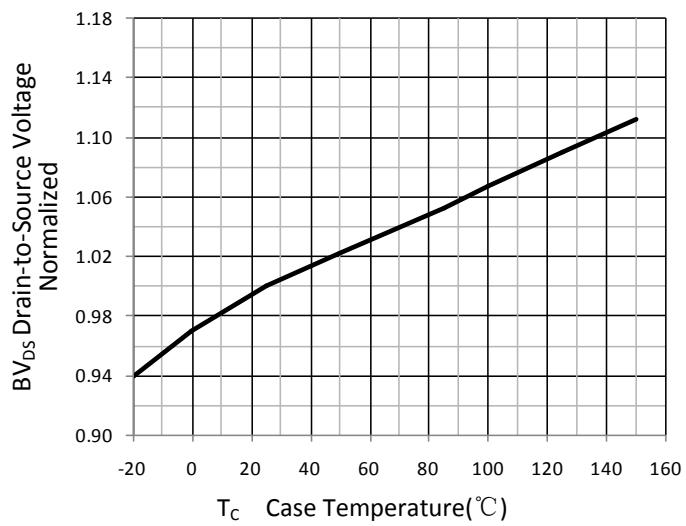
**Figure 7.** Typical Source-Drain Diode Forward Voltage



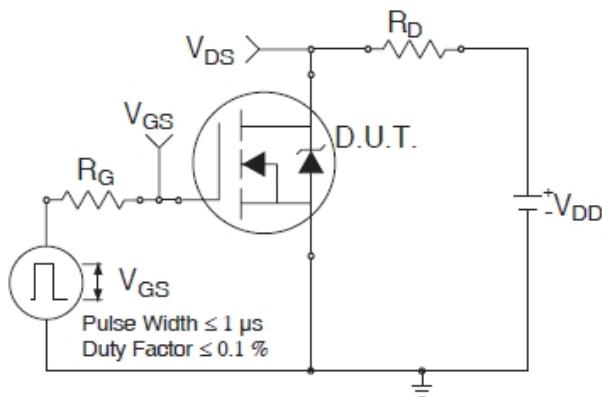
**Figure 8.** Maximum Safe Operating Area



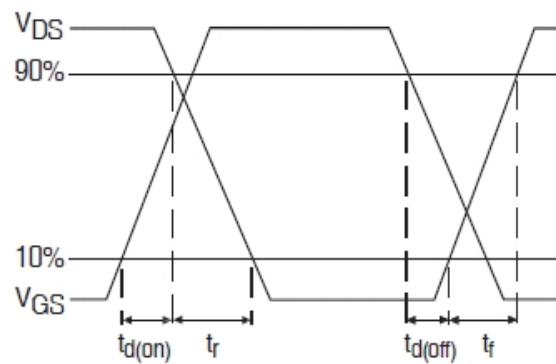
**Figure 9.** Maximum Drain Current Vs Temperature



**Figure 10.** Normalized Drain-Source Voltage Vs Temperature

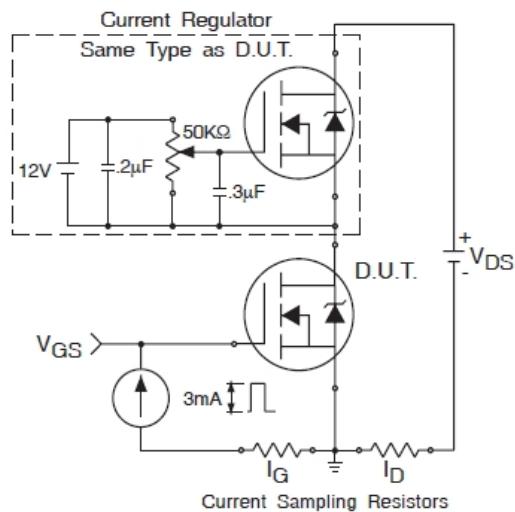


**Figure 11a.** Switching Time Test Circuit

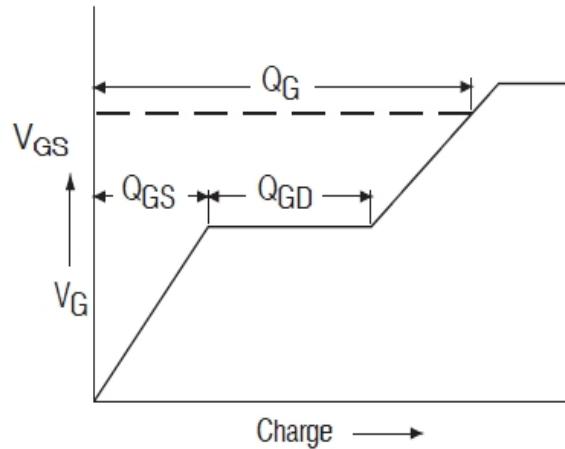


**Figure 11b.** Switching Time Waveforms

## Typical Characteristics Diagrams

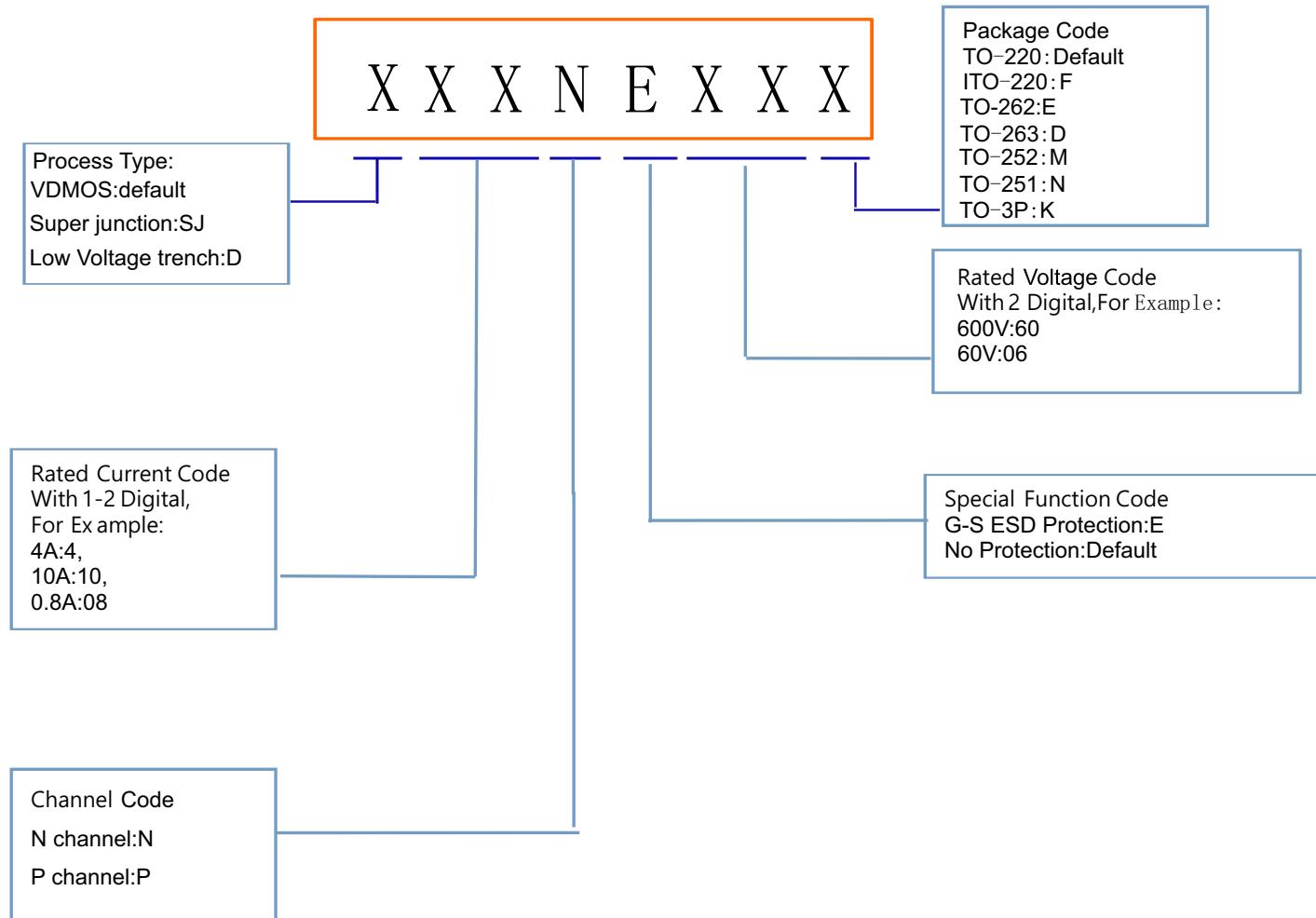


**Figure 12a.** Gate Charge Test Circuit



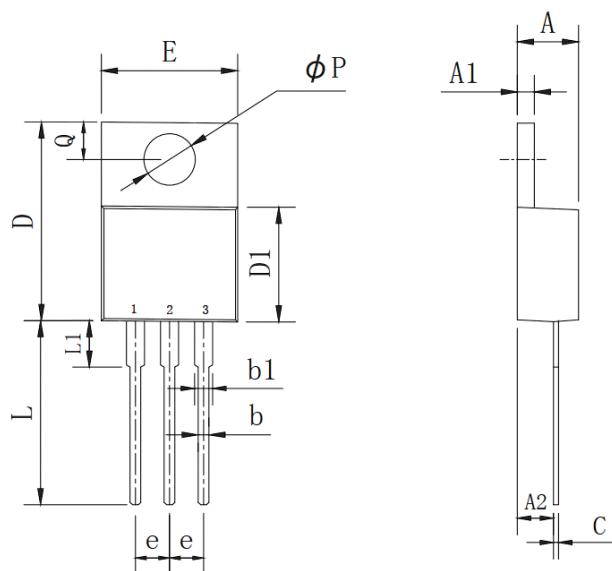
**Figure 12b.** Basic Gate Charge Waveforms

## Product Names Rules



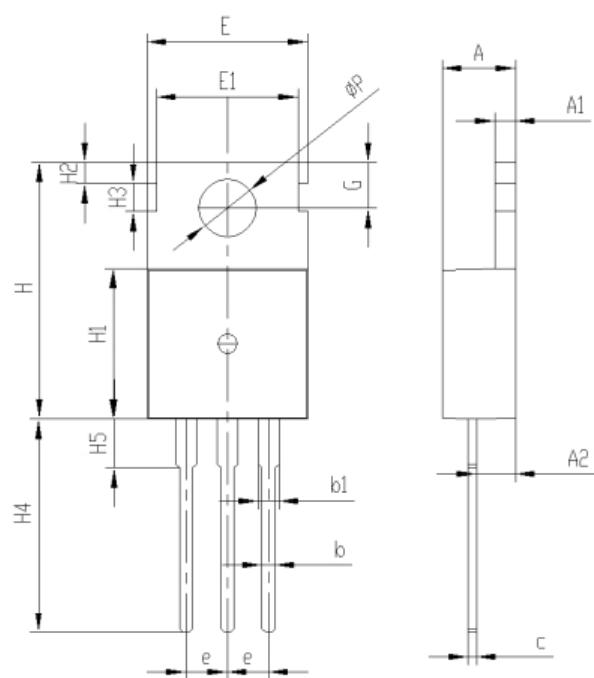
## Dimensions

## TO-220 PACKAGE OUTLINE DIMENSIONS



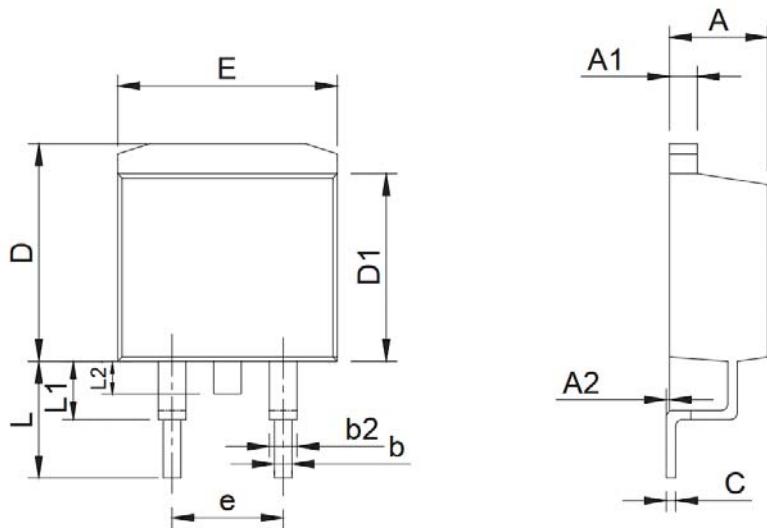
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.25	4.87	0.167	0.192
A1	1.07	1.47	0.042	0.058
A2	2.03	2.92	0.080	0.115
b	0.51	1.11	0.020	0.044
b1	0.97	1.6	0.038	0.063
C	0.3	0.7	0.012	0.028
D	14.6	15.9	0.575	0.626
D1	8.04	9.3	0.317	0.366
E	9.57	10.57	0.377	0.416
e	2.34	2.74	0.092	0.108
L	12.58	14.3	0.495	0.563
L1	2.8	4.2	0.110	0.165
P	3.4	4.14	0.134	0.163
Q	2.45	3	0.096	0.118

## TO-220C PACKAGE OUTLINE DIMENSIONS



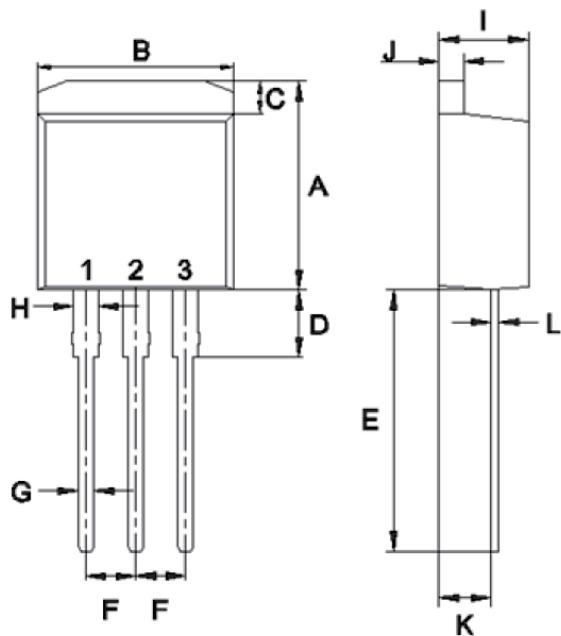
Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.30	4.70
A1	1.17	1.37
A2	2.20	2.60
b	0.60	1.00
b1	1.17	1.37
b2	1.90	2.30
c	0.30	0.70
e	2.34	2.74
E	9.70	10.1
E1	8.50	8.90
H	15.5	15.9
H1	9.00	9.40
H2	1.10	1.50
H3	1.50	1.90
H4	12.58	13.58
H5	2.80	3.20
G	2.60	3.00
ΦP	3.40	3.80

## TO-263 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.25	4.87	0.167	0.192
A1	1.07	1.47	0.042	0.058
A2	0	0.25	0.000	0.010
b	0.61	1.01	0.024	0.040
b1	1.2	1.34	0.047	0.053
C	0.3	0.6	0.012	0.024
D	9.48	10.84	0.373	0.427
D1	8.49	9.3	0.334	0.366
E	9.7	10.31	0.382	0.406
e	4.88	5.28	0.192	0.208
L	4.46	5.85	0.176	0.230
L1	1.33	2.33	0.052	0.092
L2	0	2.2	0.000	0.087

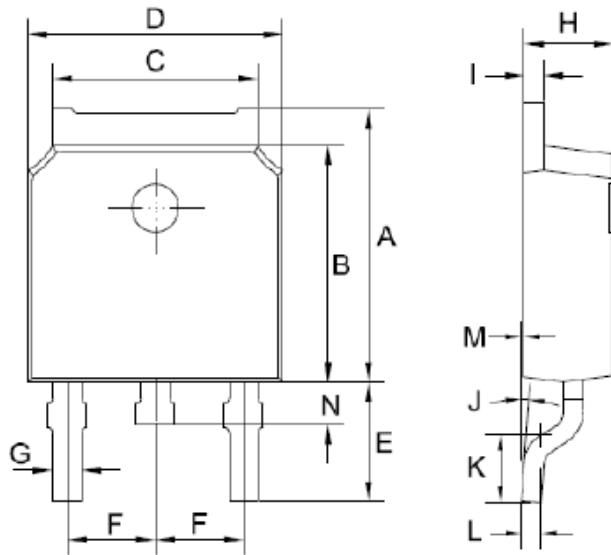
## TO-262 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	10.14	11.14	0.399	0.439
B	9.57	10.57	0.377	0.416
C	1.15	1.84	0.045	0.072
D	2.95	3.95	0.116	0.156
E	12.25	13.75	0.482	0.541
F	2.34	2.74	0.092	0.108
G	0.51	1.11	0.020	0.044
H	0.97	1.57	0.038	0.062
I	4.25	4.87	0.167	0.192
J	1.07	1.47	0.042	0.058
K	2.03	2.92	0.080	0.115
L	0.3	0.6	0.012	0.024

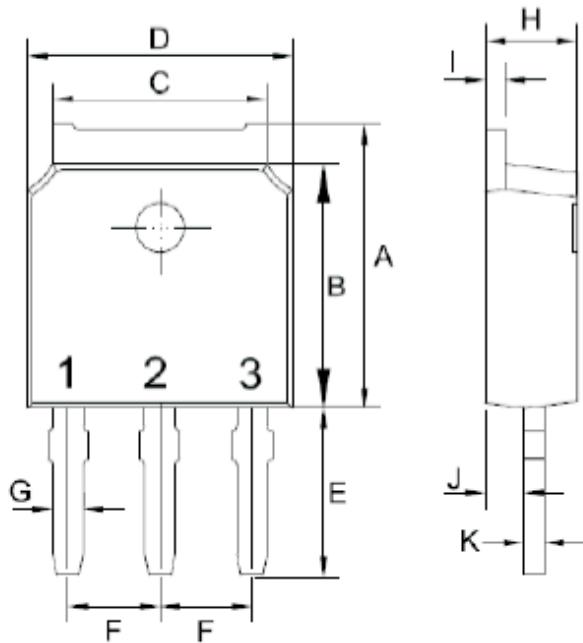
## Dimensions

## TO-252 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	2.6	3.3	0.102	0.130
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0°	8°	0°	8°
K	1.45	1.85	0.057	0.073
L	0.41	0.61	0.016	0.024
M	0	0.12	0.000	0.005
P	0.6	1	0.024	0.039

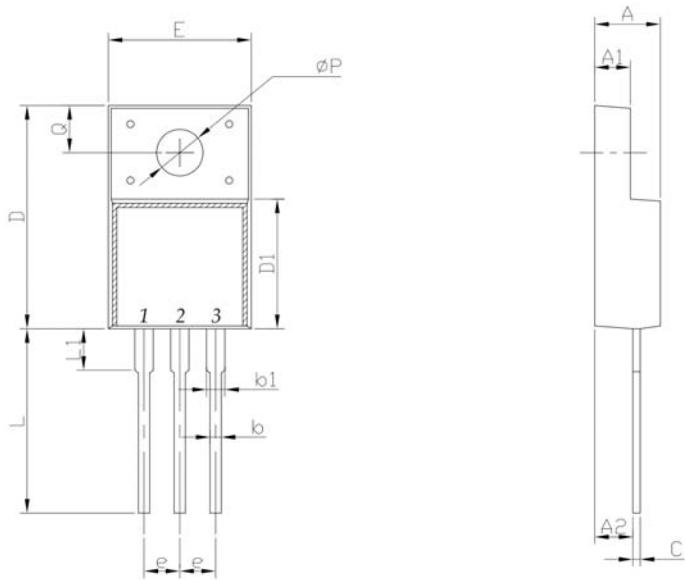
## TO-251 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	3.5	4.35	0.138	0.171
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0.71	1.31	0.028	0.052
K	0.41	0.61	0.016	0.024

## Dimensions

## ITO-220 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.24	4.9	0.167	0.193
A1	2.3	2.92	0.091	0.115
A2	2.61	2.81	0.103	0.111
b	0.3	1	0.012	0.039
b1	0.9	1.55	0.035	0.061
C	0.3	0.7	0.012	0.028
D	14.5	16.36	0.571	0.644
D1	8.8	9.41	0.346	0.370
E	9.5	10.5	0.374	0.413
e	2.3	2.75	0.091	0.108
L	12.6	14	0.496	0.551
L1	2.45	4.3	0.096	0.169
P	2.9	3.8	0.114	0.150
Q	2.5	3.55	0.098	0.140

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